

# MXTA77

CASE 345-01, STYLE 1  
SOT-89

DARLINGTON TRANSISTOR

PNP SILICON

## MAXIMUM RATINGS

| Rating                         | Symbol    | Value | Unit |
|--------------------------------|-----------|-------|------|
| Collector-Emitter Voltage      | $V_{CES}$ | 60    | V    |
| Emitter-Base Voltage           | $V_{EBO}$ | 10    | V    |
| Collector Current — Continuous | $I_C$     | 300   | mA   |

## THERMAL CHARACTERISTICS

| Characteristic                                                                         | Symbol          | Max        | Unit                         |
|----------------------------------------------------------------------------------------|-----------------|------------|------------------------------|
| *Total Device Dissipation, $T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | $P_D$           | 1.0<br>8.0 | Watt<br>mW/ $^\circ\text{C}$ |
| Storage Temperature                                                                    | $T_{stg}$       | 150        | $^\circ\text{C}$             |
| *Thermal Resistance Junction to Ambient                                                | $R_{\theta JA}$ | 125        | $^\circ\text{C/W}$           |

\*Package mounted on 99.5% alumina 10 x 12 x 0.6 mm.

Refer to MPSA75 for graphs.

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted.)

| Characteristic | Symbol | Min | Max | Unit |
|----------------|--------|-----|-----|------|
|----------------|--------|-----|-----|------|

### OFF CHARACTERISTICS

|                                                                     |               |    |     |    |
|---------------------------------------------------------------------|---------------|----|-----|----|
| Collector-Emitter Breakdown Voltage<br>( $I_C = 100\ \mu\text{A}$ ) | $V_{(BR)CES}$ | 60 | —   | V  |
| Collector-Base Breakdown Voltage<br>( $I_C = 100\ \mu\text{A}$ )    | $V_{(BR)CBO}$ | 60 | —   | V  |
| Collector Cutoff Current<br>( $V_{CB} = 50\ \text{V}$ )             | $I_{CBO}$     | —  | 100 | nA |
| Collector Cutoff Current<br>( $V_{CE} = 50\ \text{V}$ )             | $I_{CES}$     | —  | 500 | nA |
| Emitter Cutoff Current<br>( $V_{BE} = 10\ \text{V}$ )               | $I_{EBO}$     | —  | 100 | nA |

### ON CHARACTERISTICS

|                                                                                                                                  |               |              |        |   |
|----------------------------------------------------------------------------------------------------------------------------------|---------------|--------------|--------|---|
| DC Current Gain<br>( $I_C = 10\ \text{mA}$ , $V_{CE} = 5.0\ \text{V}$ )<br>( $I_C = 100\ \text{mA}$ , $V_{CE} = 5.0\ \text{V}$ ) | $h_{FE}$      | 10 K<br>10 K | —<br>— | — |
| Collector-Emitter Saturation Voltage<br>( $I_C = 100\ \text{mA}$ , $I_B = 0.1\ \text{mA}$ )                                      | $V_{CE(sat)}$ | —            | 1.5    | V |
| Base-Emitter On Voltage<br>( $I_C = 100\ \text{mA}$ , $V_{CE} = 5.0\ \text{V}$ )                                                 | $V_{BE(on)}$  | —            | 2.0    | V |
| Current Gain — High Frequency<br>( $I_C = 10\ \text{mA}$ , $V_{CE} = 5.0\ \text{V}$ , $f = 100\ \text{MHz}$ )                    | $ h_{fe} $    | 1.25         | —      | — |